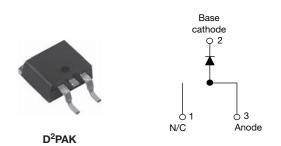
High Performance Schottky Rectifier, 15 A



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PRODUCT SUMMARY					
Package	D ² PAK				
I _{F(AV)}	15 A				
V _R	60 V				
V _F at I _F	0.56 V				
I _{RM} max.	45 mA at 125 °C				
T _J max.	150 °C				
Diode variation	Single die				
E _{AS}	6 mJ				

FEATURES

- 150 °C T_J operation
- Very low forward voltage drop
- High frequency operation
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance



FREE

- Guard ring for enhanced ruggedness and long term reliability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 qualified
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION

The VS-15TQ060SPbF Schottky rectifier has been optimized for very low forward voltage drop, with moderate leakage. The proprietary barrier technology allows for reliable operation up to 150 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS								
SYMBOL CHARACTERISTICS VALUES UNITS								
I _{F(AV)}	Rectangular waveform	15	А					
V _{RRM}		60	V					
I _{FSM}	t _p = 5 μs sine	1000	А					
V _F	15 A _{pk} , T _J = 125 °C	0.56	V					
TJ	Range	-55 to +150	°C					

VOLTAGE RATINGS						
PARAMETER SYMBOL VS-15TQ060SPbF UN						
Maximum DC reverse voltage	V _R	60	V			
Maximum working peak reverse voltage	v					

ABSOLUTE MAXIMUM RATINGS							
PARAMETER	SYMBOL	TEST CONDI	TIONS	VALUES	UNITS		
Maximum average forward current See fig. 5	I _{F(AV)}	50 % duty cycle at T _C = 104 °C	15	А			
Maximum peak one cycle non-repetitive surge current		5 µs sine or 3 µs rect. pulse	rect. pulse Following any rated load condition and with		А		
See fig. 7	IFSM	10 ms sine or 6 ms rect. pulse	rated V _{RRM} applied	260	~		
Non-repetitive avalanche energy	E _{AS}	T _J = 25 °C, I _{AS} = 1.5 A, L = 11.5 mH		6	mJ		
Repetitive avalanche current	I _{AR}	Current decaying linearly to zero Frequency limited by T _J maximu		1.50	A		

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ELECTRICAL SPECIFICATIONS							
PARAMETER	SYMBOL	TEST CO	NDITIONS	VALUES	UNITS		
		15 A	T.I = 25 °C	0.62			
Maximum forward voltage drop	V (1)	30 A	1j=25 C	0.82	V		
See fig. 1	V _{FM} ⁽¹⁾	15 A	T 105 %O	0.56			
		30 A	T _J = 125 °C	0.71			
Maximum reverse leakage current	. (1)	T _J = 25 °C	$V_{\rm B}$ = Rated $V_{\rm B}$	0.80	mA		
See fig. 2	I _{RM} ⁽¹⁾	T _J = 125 °C	V _R = naleu V _R	45	ША		
Maximum junction capacitance	CT	$V_R = 5 V_{DC}$ (test signal ran	ge 100 kHz to 1 MHz), 25 °C	720	pF		
Typical series inductance	L _S	Measured lead to lead 5 r	mm from package body	8.0	nH		
Maximum voltage rate of change	dV/dt	Rated V _R		10 000	V/µs		

Note

 $^{(1)}$ Pulse width < 300 $\mu s,$ duty cycle < 2 %

THERMAL - MECH	THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Maximum junction and sto temperature range	orage	T _J , T _{Stg}		-55 to +150	°C		
Maximum thermal resistance, junction to case		R _{thJC}	DC operation See fig. 4	3.25	°C/W		
Typical thermal resistance, case to heatsink		R _{thCS}	Mounting surface, smooth and greased	0.50	0,77		
Approximate weight				2	g		
Approximate weight				0.07	oz.		
Mounting torque minimum maximum				6 (5)	kgf ⋅ cm		
				12 (10)	(lbf ∙ in)		
Marking device			Case style D ² PAK	15TQ	060S		

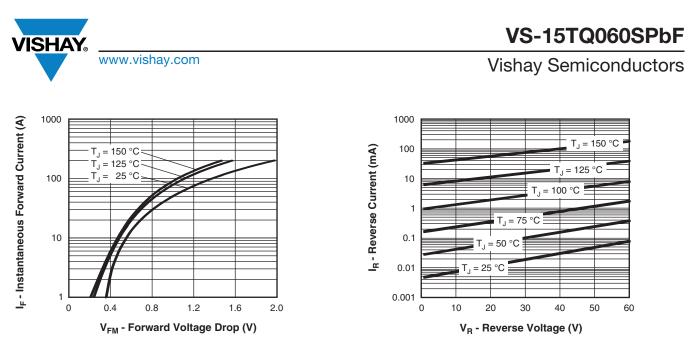


Fig. 1 - Maximum Forward Voltage Drop Characteristics

Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

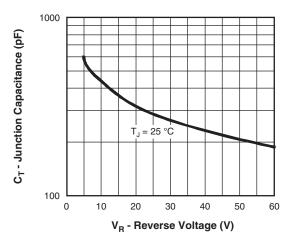


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

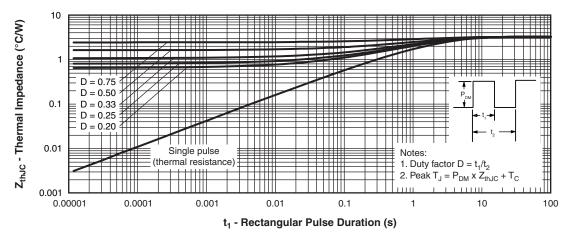


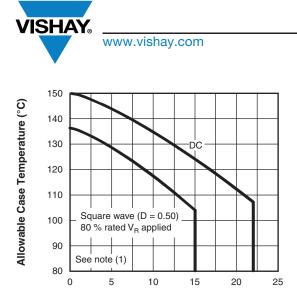
Fig. 4 - Maximum Thermal Impedance ZthJC Characteristics

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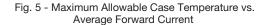
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I_{F(AV)} - Average Forward Current (A)



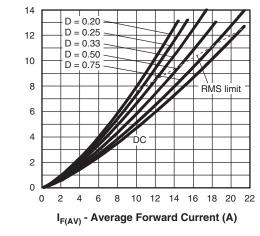
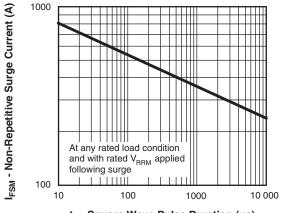


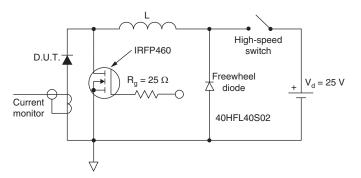
Fig. 6 - Forward Power Loss Characteristics



Average Power Loss (W)

t_p - Square Wave Pulse Duration (μs)

Fig. 7 - Maximum Non-Repetitive Surge Current





Note

- ⁽¹⁾ Formula used: $T_C = T_J (Pd + Pd_{REV}) \times R_{thJC}$;

 - $\begin{array}{l} \mathsf{Pd} = \mathsf{Forward} \ \mathsf{power} \ \mathsf{loss} = \mathsf{I}_{\mathsf{F}(\mathsf{AV})} \times \mathsf{V}_{\mathsf{FM}} \ \mathsf{at} \ (\mathsf{I}_{\mathsf{F}(\mathsf{AV})}/\mathsf{D}) \ (\mathsf{see} \ \mathsf{fig.} \ \mathsf{6}); \\ \mathsf{Pd}_{\mathsf{REV}} = \mathsf{Inverse} \ \mathsf{power} \ \mathsf{loss} = \mathsf{V}_{\mathsf{R1}} \times \mathsf{I}_{\mathsf{R}} \ (\mathsf{1} \mathsf{D}); \ \mathsf{I}_{\mathsf{R}} \ \mathsf{at} \ \mathsf{V}_{\mathsf{R1}} = \mathsf{80} \ \% \ \mathsf{rated} \ \mathsf{V}_{\mathsf{R}} \end{array}$

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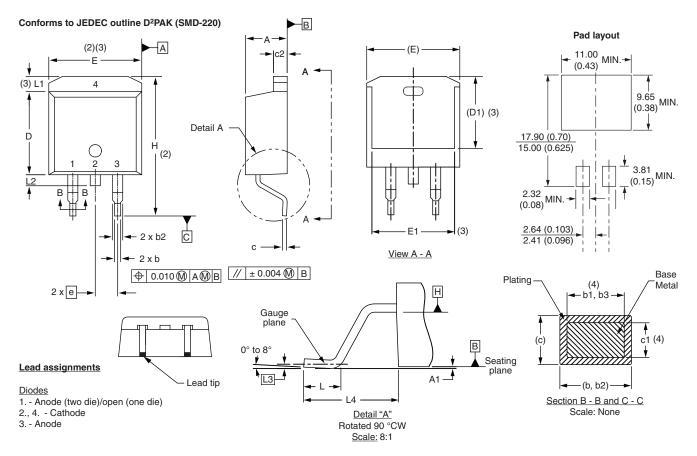


ORDERING INFORMATION TABLE

Device code	VS-	15	т	Q	060	S	TRL	PbF
	1	2	3	4	5	6	(7)	8
	1 - 2 - 3 - 4 - 5 - 6 -	Cur Circ Sch Volt	rent rati cuit conf iottky "C	niconduo ng (15 A iguratior " series ng (060	N) n: T = T(D-220		
	7 -	• TI	RL = tap	be (50 p be and re	eel (left		,	
	8 -		-	be and r (Pb)-fre		nt orient	ed)	

LINKS TO RELATED DOCUMENTS					
Dimensions <u>www.vishay.com/doc?95014</u>					
Part marking information	www.vishay.com/doc?95008				
Packaging information	www.vishay.com/doc?95032				
SPICE model	www.vishay.com/doc?95600				

D²PAK, TO-262



DIMENSIONS - D²PAK in millimeters and inches

SHA

SYMBOL	MILLIN	IETERS	INC	HES	NOTES
STIVIDOL	MIN.	MAX.	MIN.	MAX.	NOTES
А	4.06	4.83	0.160	0.190	
A1	0.00	0.254	0.000	0.010	
b	0.51	0.99	0.020	0.039	
b1	0.51	0.89	0.020	0.035	4
b2	1.14	1.78	0.045	0.070	
b3	1.14	1.73	0.045	0.068	4
с	0.38	0.74	0.015	0.029	
c1	0.38	0.58	0.015	0.023	4
c2	1.14	1.65	0.045	0.065	
D	8.51	9.65	0.335	0.380	2

CVMDOI					NOTES
SYMBOL	MIN.	MAX.	MIN.	MAX.	NOTES
D1	6.86	8.00	0.270	0.315	3
E	9.65	10.67	0.380	0.420	2, 3
E1	7.90	8.80	0.311	0.346	3
е	2.54	BSC	0.100	BSC	
Н	14.61	15.88	0.575	0.625	
L	1.78	2.79	0.070	0.110	
L1	-	1.65	-	0.066	3
L2	1.27	1.78	0.050	0.070	
L3	0.25	BSC	0.010	BSC	
L4	4.78	5.28	0.188	0.208	
L4	4.70	5.20	0.100	0.200	

INCHES

NOTES

MILLIMETERS

⁽⁷⁾ Outline conforms to JEDEC outline TO-263AB

Notes

⁽¹⁾ Dimensioning and tolerancing per ASME Y14.5 M-1994

⁽²⁾ Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body

- ⁽³⁾ Thermal pad contour optional within dimension E, L1, D1 and E1
- ⁽⁴⁾ Dimension b1 and c1 apply to base metal only
- ⁽⁵⁾ Datum A and B to be determined at datum plane H

⁽⁶⁾ Controlling dimension: inch

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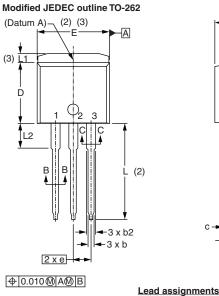
Outline Dimensions

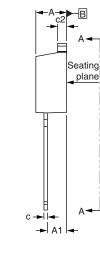
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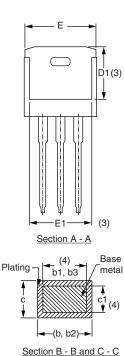
D²PAK, TO-262



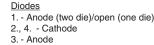
DIMENSIONS - TO-262 in millimeters and inches

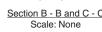






Lead tip





(6) Outline conform to JEDEC TO-262 except A1 (maximum), b (minimum) and D1 (minimum) where dimensions derived the

actual package outline

SYMBOL	MILLIN	MILLIMETERS		INCHES		
STWDUL	MIN.	MAX.	MIN.	MAX.	NOTES	
А	4.06	4.83	0.160	0.190		
A1	2.03	3.02	0.080	0.119		
b	0.51	0.99	0.020	0.039		
b1	0.51	0.89	0.020	0.035	4	
b2	1.14	1.78	0.045	0.070		
b3	1.14	1.73	0.045	0.068	4	
С	0.38	0.74	0.015	0.029		
c1	0.38	0.58	0.015	0.023	4	
c2	1.14	1.65	0.045	0.065		
D	8.51	9.65	0.335	0.380	2	
D1	6.86	8.00	0.270	0.315	3	
E	9.65	10.67	0.380	0.420	2, 3	
E1	7.90	8.80	0.311	0.346	3	
e	2.54	BSC	0.100	BSC		
L	13.46	14.10	0.530	0.555		
L1	-	1.65	-	0.065	3	
L2	3.56	3.71	0.140	0.146		

Notes

- ⁽¹⁾ Dimensioning and tolerancing as per ASME Y14.5M-1994
- ⁽²⁾ Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body
- ⁽³⁾ Thermal pad contour optional within dimension E, L1, D1 and E1
- ⁽⁴⁾ Dimension b1 and c1 apply to base metal only

⁽⁵⁾ Controlling dimension: inches

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